

**Features**

- Output Current: 200mA or more
- Dropout Voltage: 150mV@200mA
- Operating Voltage Range: 1.8V-5.5V
- Output Voltage Range: 1.2V-4.5V(100 mV Step)
- High Accuracy: ±2.0%
- Low Power Consumption: 55 µA
- Standby Current: 0.1µA
- High Ripple Rejection: 70dB@ 1kHz
- Output Current-Limit Protection
- Short Circuit Protection
- Optional Auto Output Discharge
- Operating Temperature Range: -40 ~ +85
- Low ESR Capacitor Compatible: Ceramic Capacitor
- Thermal Shutdown Protection
- Package: SOT23-6L

**Application**

- Mobile phones (PDC, GSM, CDMA, IMT2000 etc.)
- Cordless phones and radio communication equipment
- Digital still cameras and video cameras
- PDAs
- MP3 players
- Portable devices

**Description**

The PT7M8424 series are highly accurate, dual, low dropout voltage regulators with low noise, high ripple rejection and low current consumption.

The PT7M8424 includes a reference voltage source, error amplifiers, driver transistors, individual enable inputs, current limit protections, short circuit protections, thermal shutdown protection and internal phase compensators.

The output voltage for each regulator is set by factory trimming within a range of 1.2V to 4.5V in 100mV step. The PT7M8424 series are stable with low ESR ceramic capacitors. The PT7M8424 series are available in the SOT23-6L package.

**Ordering Information**

Part Number		Package
PT7M8424	TA6E	Lead free and Green SOT23-6L

Note: “ ” refer to different functions. See below Table 1.

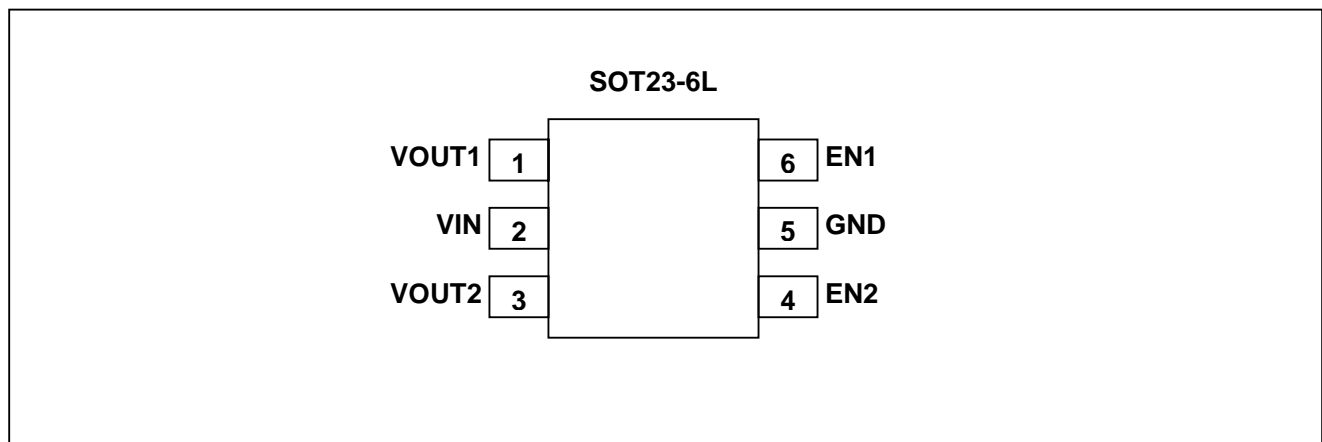
**Table 1 PT7M8424 Options**

Designator	Symbol	Description	Designator	Symbol	Description
Regulators 1 and 2 EN type	AA	High active with pull-down resistor, with auto output discharge	Regulator 1 Output voltage	12-45	Internally set sequential number relating output voltage of regulator 1 Regulator 1 Output Voltage Range: 1.2~ 4.5V, the detail is in Table 2.
	BB	High active without pull-down resistor, with auto output discharge		2A	
	CC	Low active with pull-up resistor, with auto output discharge			
	DD	Low active without pull-up resistor, with auto output discharge			
	EE	High active with pull-down resistor, without auto output discharge	Regulator 2 Output voltage	12-45	Internally set sequential number relating output voltage of regulator 2 Regulator 2 Output Voltage Range: 1.2~ 4.5V, the detail is in Table 2.
	FF	High active without pull-down resistor, without auto output discharge		2A	
	GG	Low active with pull-up resistor, without auto output discharge			
	HH	Low active without pull-up resistor, without auto output discharge			

**Table 2 Sequential Number Description**

Designator	V <sub>OUT1</sub> or V <sub>OUT2</sub> (V)	Designator	V <sub>OUT1</sub> or V <sub>OUT2</sub> (V)	Designator	V <sub>OUT1</sub> or V <sub>OUT2</sub> (V)	Designator	V <sub>OUT1</sub> or V <sub>OUT2</sub> (V)
		21	2.1	31	3.1	41	4.1
12	1.2	22	2.2	32	3.2	42	4.2
13	1.3	23	2.3	33	3.3	43	4.3
14	1.4	24	2.4	34	3.4	44	4.4
15	1.5	25	2.5	35	3.5	45	4.5
16	1.6	26	2.6	36	3.6	2A	2.85
17	1.7	27	2.7	37	3.7		
18	1.8	28	2.8	38	3.8		
19	1.9	29	2.9	39	3.9		
20	2.0	30	3.0	40	4.0		

**Pin Assignment**



**Pin Description**

Pin No.	Pin Name	Description
1	VOUT1	Output of Regulator 1. Bypass with a 1μF ceramic capacitor (X5R/X7R) to GND.
2	VIN	Regulators Supply Input. Supply voltage can range from 1.8V to 5.5V. Bypass with a 1μF ceramic capacitor (X5R/X7R) to GND.
3	VOUT2	Output of Regulator 2. Bypass with a 1μF ceramic capacitor (X5R/X7R) to GND.
4	EN2	ON/OFF Control of Regulator 2.
5	GND	Ground.
6	EN1	ON/OFF Control of Regulator 1.

**Functional Description** (Refer to Block Diagram)

**Output Voltage**

The divided output voltage is compared with the internal reference voltage by the error amplifier with internal phase compensator. The output of the error amplifier then drives the P-channel MOSFET to maintain a stable and constant output voltage.

**Low ESR Capacitors**

The internal phase compensator maintains the stable output voltage with low ESR ceramic input and output capacitors. 1µF low ESR (X5R/X7R) ceramic capacitors located as close as possible to the IC’s pins is recommended.

**Current Limit , Short Circuit Protection and Thermal Shutdown Protection**

Current limit protection is used to limit the output current when an overload condition occurs. As a result, the output voltage will drop. When the overload condition is getting worse and the output voltage is close to ground, the short circuit protection will further reduce the output current to a very low level to reduce the power dissipation in the IC. Thermal shutdown protection will turn off the output to reduce the power dissipation when the operation junction temperature exceeds 160°C.

**EN Pins**

The outputs of the two regulators can be controlled independently with the EN1 and EN2 pins. When a regulator is disabled, the output voltage is discharged by internal feedback resistor and the circuitry of the regulator will not consume power. In the IC with auto output discharge option, the output voltage is also discharged quickly by a pull-low transistor. For the IC with EN type of “without pull-up/down resistor”, the EN pin should be connected to a “VIN” or a “GND” voltage as a floating input applied to inverter input of the enable circuitry will increase the current consumption.

■ **NOTE ON USE**

1. Please use this IC within the stated absolute maximum ratings.
2. Where wiring impedance is high, operations may become unstable due to noise and/or phase lag depending on output current. Please keep the resistance low between VIN and GND wiring in particular.
3. Please wire the input capacitor (C<sub>IN</sub>) and the output capacitors (C<sub>OUT1</sub>, C<sub>OUT2</sub>) as close to the IC as possible.

**Maximum Ratings**

Storage Temperature.....	- 55°C to +125°C
Ambient Temperature with Power Applied.....	-40°C to +85°C
Input Voltage .....	+6.0V
Output Voltage .....	- 0.3 to V <sub>CC</sub> +0.3V
EN pin Voltage .....	+6.0V
DC Input/Output Current .....	700mA
Power Dissipation.....	250mW

**Note:**  
 Stresses greater than those listed under MAXIMUM RATINGS may cause permanent damage to the device. This is a stress rating only and functional operation of the device at these or any other conditions above those indicated in the operational sections of this specification is not implied. Exposure to absolute maximum rating conditions for extended periods may affect reliability.

**Electrical Characteristics**

Regulator 1, Regulator 2  $T_A=25$

PARAMETER	SYMBOL	CONDITIONS	MIN	TYP	MAX	UNIT	
Output Voltage	$V_{OUT(E)}$	$V_{IN}=V_{OUT(T)}+1.0V$ $I_{OUT}=30mA$	$V_{OUT(T)}^*$ 0.98	$V_{OUT(T)}$	$V_{OUT(T)}$ *1.02	V	
Maximum Output Current	$I_{OUTMAX}$	$V_{IN}=V_{OUT(T)}+1.0V$	200	-	-	mA	
Load Regulation	$\Delta V_{OUT}$	$1mA \leq I_{OUT} \leq 200mA$	-	30	60	mV	
Dropout Voltage	$V_{dif1}$	$I_{OUT}=30mA$	$1.7V \leq V_{OUT(T)} \leq 1.8V$	-	0.05	0.10	V
			$1.9V \leq V_{OUT(T)} \leq 2.7V$	-	0.03	0.06	
			$2.8V \leq V_{OUT(T)} \leq 4.5V$	-	0.02	0.04	
	$V_{dif2}$	$I_{OUT}=200mA$	$1.7V \leq V_{OUT(T)} \leq 1.8V$	-	0.30	0.60	V
			$1.9V \leq V_{OUT(T)} \leq 2.7V$	-	0.19	0.38	
			$2.8V \leq V_{OUT(T)} \leq 4.5V$	-	0.15	0.30	
Supply Current	$I_{SS}$	$V_{IN}=V_{OUT(T)}+1.0V$ $I_{OUT}=0mA$	-	55	85	$\mu A$	
Standby Current	$I_{STB}$	$V_{IN}=V_{OUT(T)}+1.0V$ $V_{EN}=0V$	-	0.1	1	$\mu A$	
Line Regulation	$\frac{\Delta V_{OUT}}{\Delta V_{IN}} * V_{OUT}$	$V_{OUT(T)}+1.0V \leq V_{IN} \leq 6.0V$ $V_{EN}=V_{IN}$ , $I_{OUT}=30mA$	-	0.05	0.20	%/V	
Input Voltage	$V_{IN}$		1.8	-	5.5	V	
Output Voltage Temperature Characteristic	$\frac{\Delta V_{OUT}}{\Delta T_{opr}} * V_{OUT}$	$I_{OUT}=30mA$ $-40 \leq T_{opr} \leq 85$	-	$\pm 100$	-	ppm/	
Ripple Rejection	PSRR	$V_{IN}=[V_{OUT(T)}+1.0]V_{DC}+1V_{p-p} AC$ $I_{OUT}=30mA$ , $f=1kHz$	-	70	-	dB	
Current Limit	$I_{lim}$	$V_{IN}=V_{OUT(T)}+1.0V$ $V_{EN}=V_{IN}$	-	300	-	mA	
Short-Circuit Current	$I_{short}$	$V_{IN}=V_{OUT(T)}+1.0V$ $V_{EN}=V_{IN}$	-	50	-	mA	
Thermal shutdown	TSD		-	160	-		
Thermal Shutdown Hysteresis	TSD		-	20	-		
EN"High"Voltage	$V_{ENH}$		1.5	-	-	V	
EN"Low"Voltage	$V_{ENL}$		-	-	0.3	V	
EN"High"Current	$I_{ENH}$	$V_{IN}=V_{OUT(T)}+1.0V$	-0.10	-	0.10	$\mu A$	
EN"Low" Current	$I_{ENL}$	$V_{IN}=V_{OUT(T)}+1.0V$ $V_{EN}=0V$	-0.10	-	0.10	$\mu A$	
Pull-Down or Push-Up Resistance for EN Pin	$R_{PD}$		0.5	1.0	2.0	$M\Omega$	
Low Output Nch Tr. ON Resistance	$R_{LOW}$	$V_{IN}=V_{OUT(T)}+1.0V$ $V_{EN}=0V$	-	500	-	$\Omega$	

**Note:**

\*1 :  $V_{OUT(T)}$ =Specified output voltage

\*2 :  $V_{OUT(E)}$ =Effective output voltage

(I.e. the output voltage when "V<sub>OUT(T)</sub> + 1.0V" is provided at the V<sub>IN</sub> pin while maintaining a certain I<sub>OUT</sub> value).

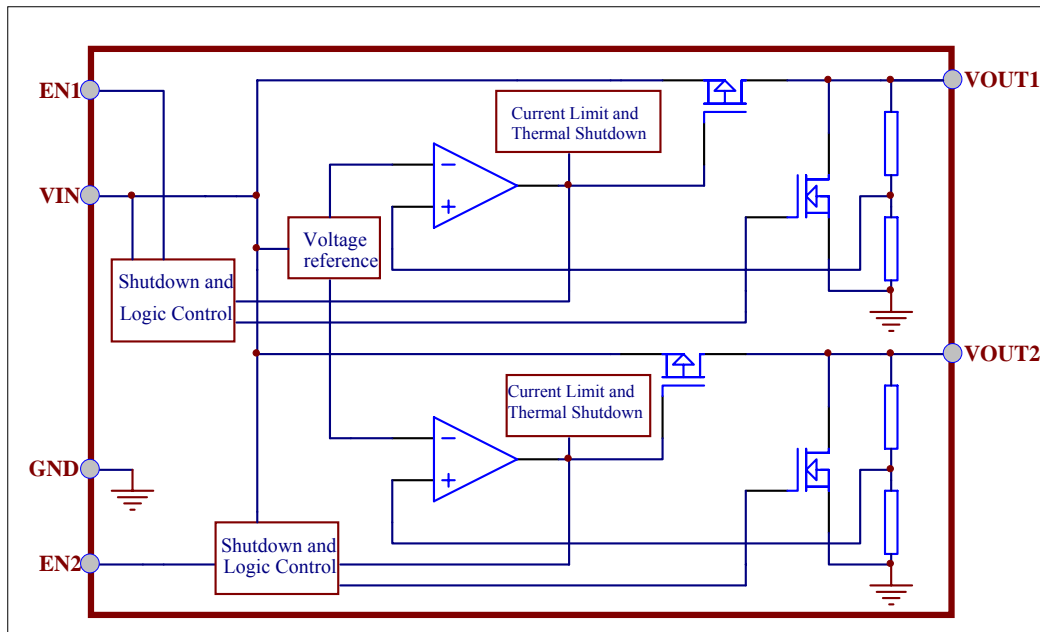
\*3 :  $V_{dif}=\{V_{IN1}^{(95)}-V_{OUT1}^{(95)}\}$

\*4 :  $V_{OUT1}$ =A voltage equal to 98% of the output voltage whenever an amply stabilized I<sub>OUT</sub> {V<sub>OUT(T)</sub>+1.0V} is input.

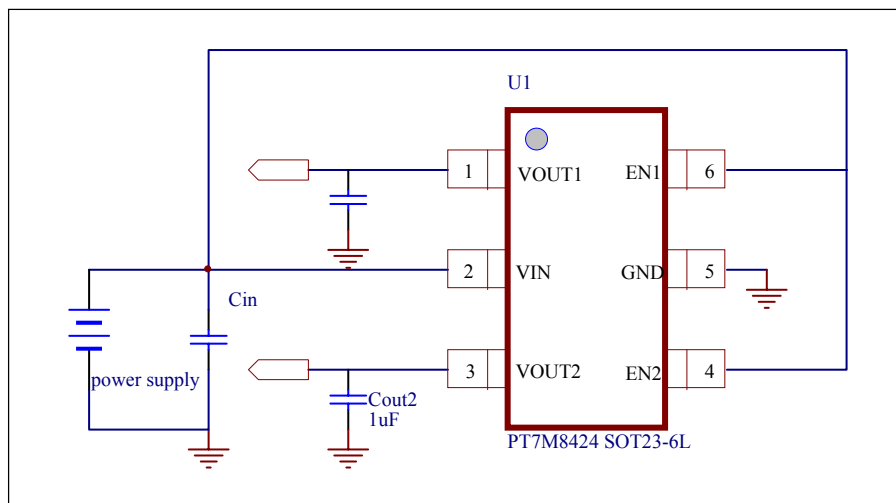
\*5 :  $V_{IN1}$ =The input voltage when V<sub>OUT1</sub> appears as input voltage is gradually decreased.

\*6 : Unless otherwise stated,  $V_{IN}=V_{OUT(T)}+1.0V$

**Block Diagram**



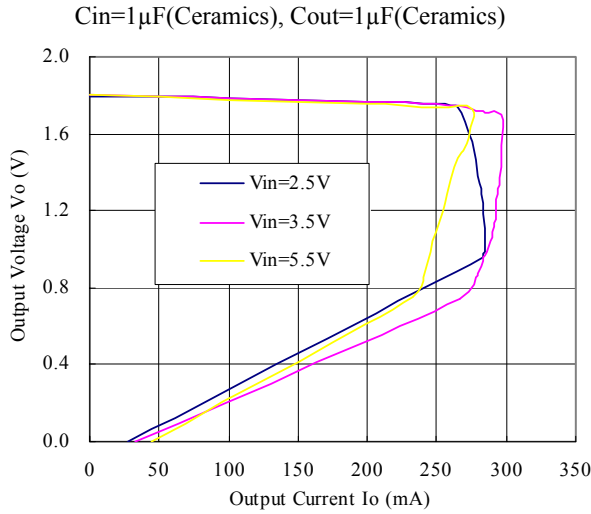
**Application Circuit**



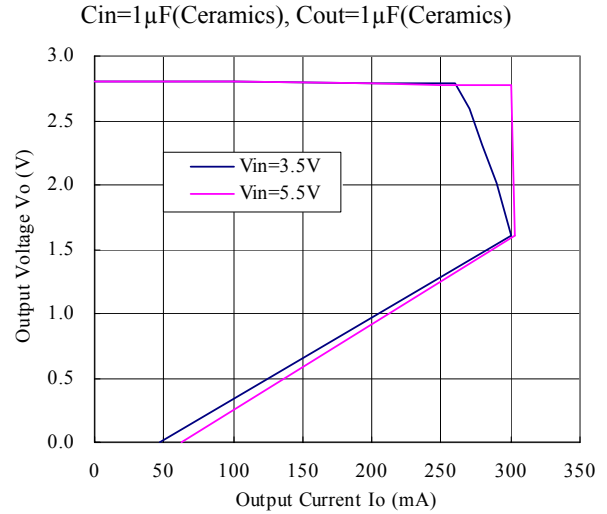
**Typical Performance Characteristics**

**1. Output Voltage vs. Output Current**

**PT7M8424 (1.8V)**

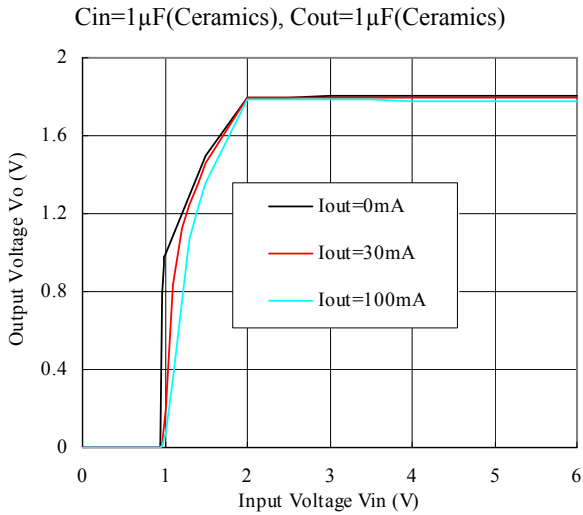


**PT7M8424 (2.8V)**

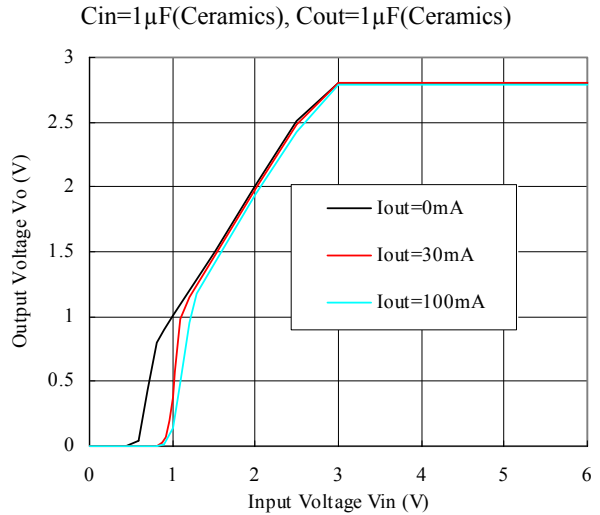


**2. Output Voltage vs. Input Voltage**

**PT7M8424 (1.8V)**

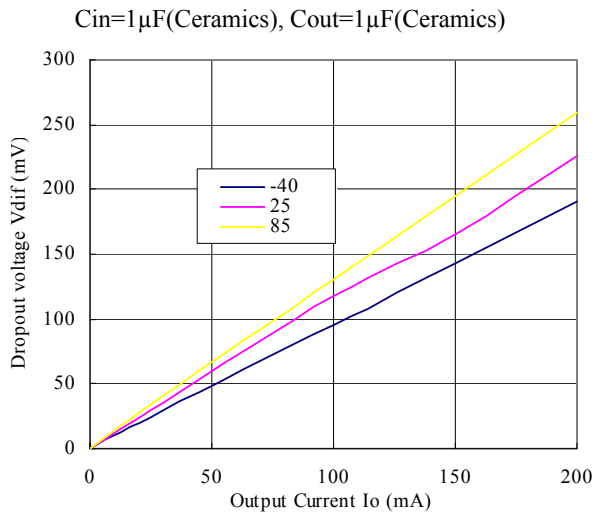


**PT7M8424 (2.8V)**

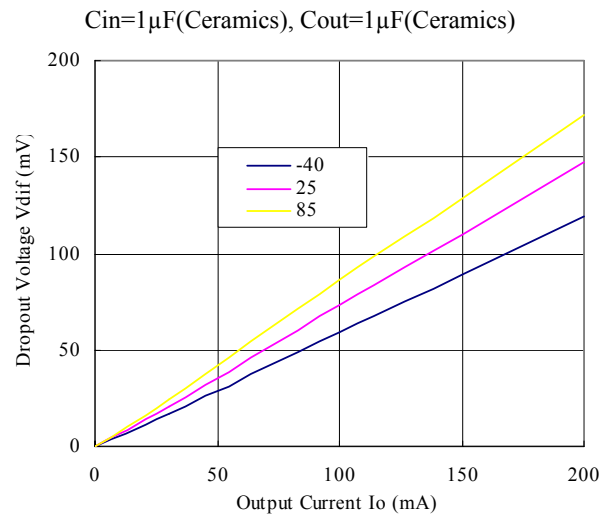


**3. Dropout Voltage vs. Output Current**

**PT7M8424 (1.8V)**

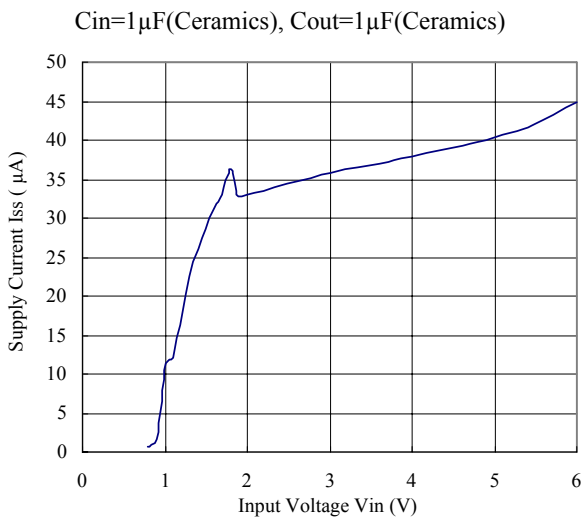


**PT7M8424 (2.8V)**

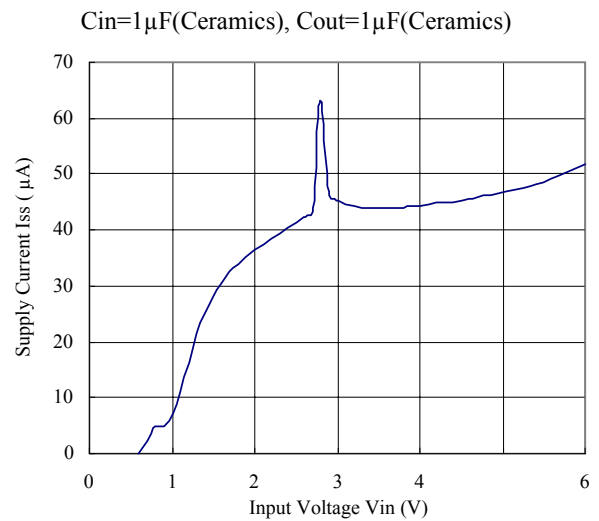


**4. Supply Current vs. Input Voltage**

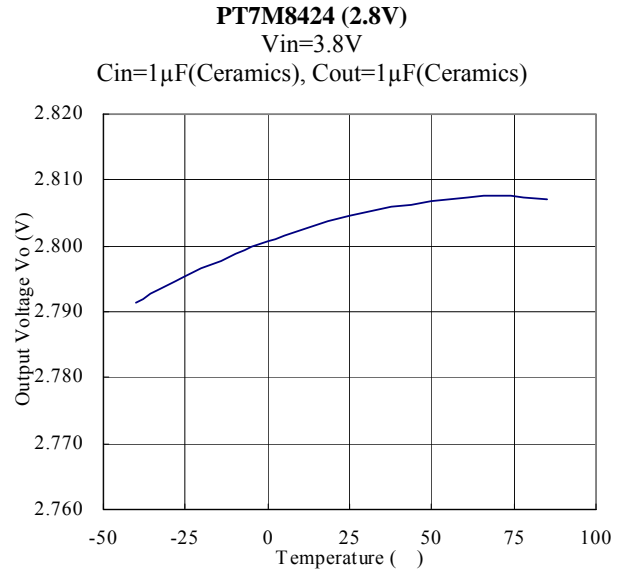
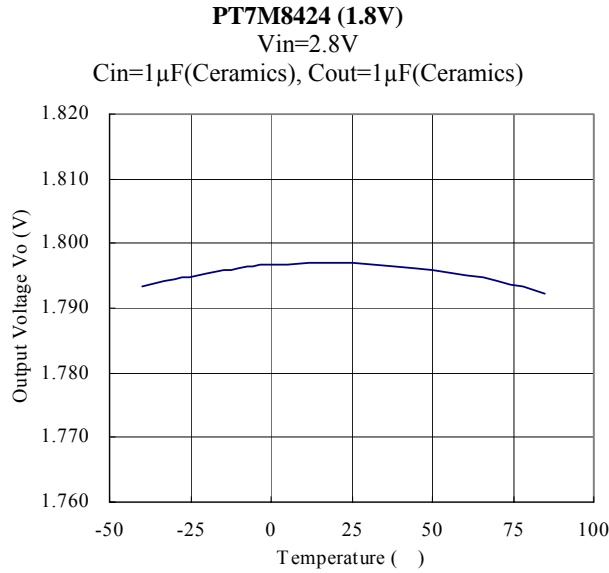
**PT7M8424 (1.8V)**



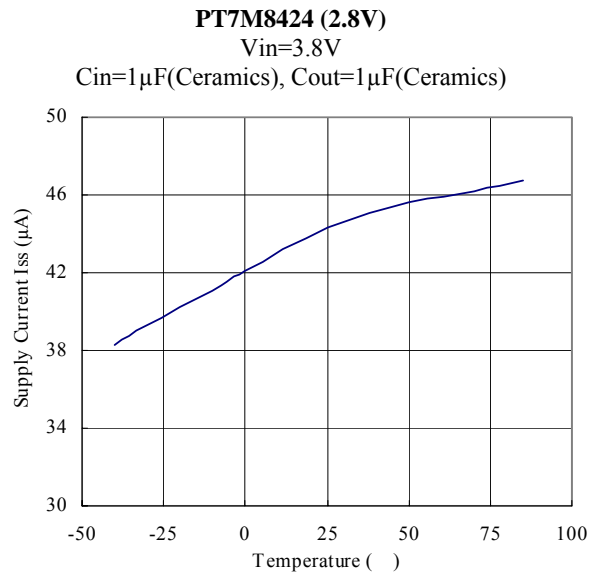
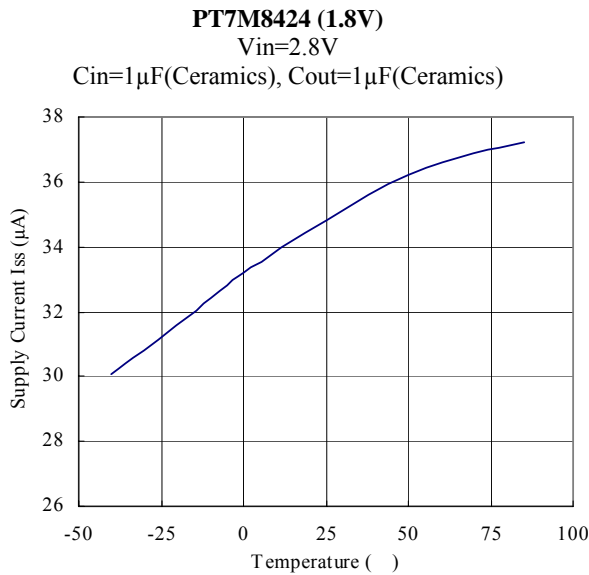
**PT7M8424 (2.8V)**



**5. Output Voltage vs. Ambient Temperature**



**6. Supply Current vs. Ambient Temperature**

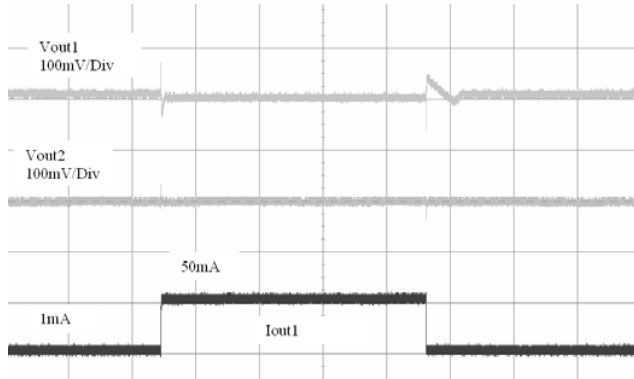




**7. Load Transient Response and Cross Talk**

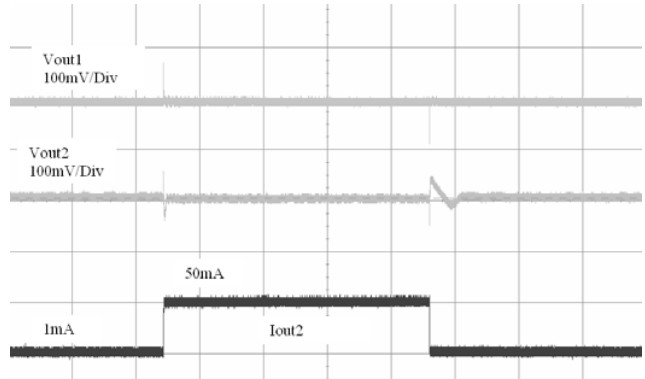
**PT7M8424 (1.8V)**

Vout1=1.8V, Vout2=2.8V, 100µs/div  
 Cin= Cout=1µF(Ceramics), Vin=3.3V, tr=tf=1µs



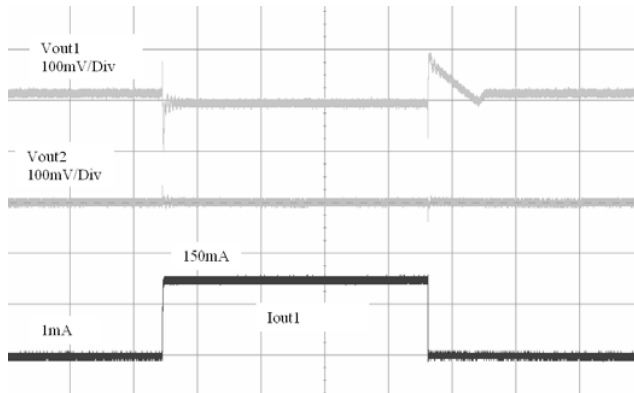
**PT7M8424 (2.8V)**

Vout1=1.8V, Vout2=2.8V, 100µs/div  
 Cin= Cout=1µF(Ceramics), Vin=3.3V, tr=tf=1µs



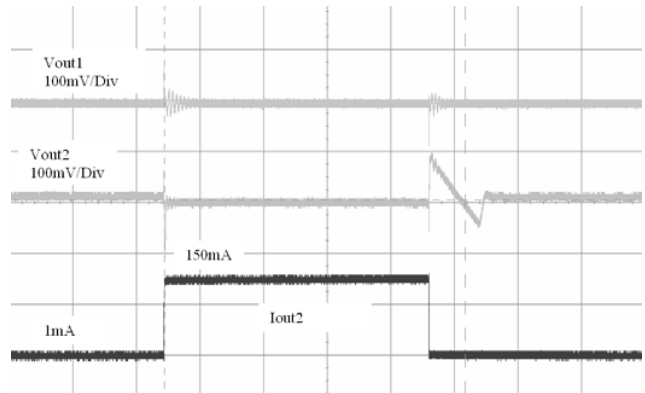
**PT7M8424 (1.8V)**

Vout1=1.8V, Vout2=2.8V, 100µs/div  
 Cin= Cout=1µF(Ceramics), Vin=3.3V, tr=tf=1µs



**PT7M8424 (2.8V)**

Vout1=1.8V, Vout2=2.8V, 100µs/div  
 Cin= Cout=1µF(Ceramics), Vin=3.3V, tr=tf=1µs

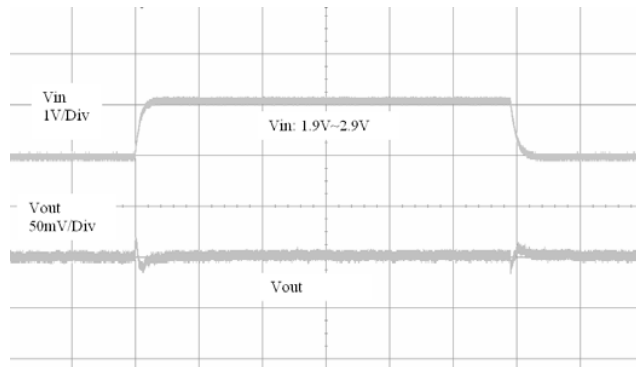


**8. Input Transient Response**

**PT7M8424 (1.8V)**

50µs/div

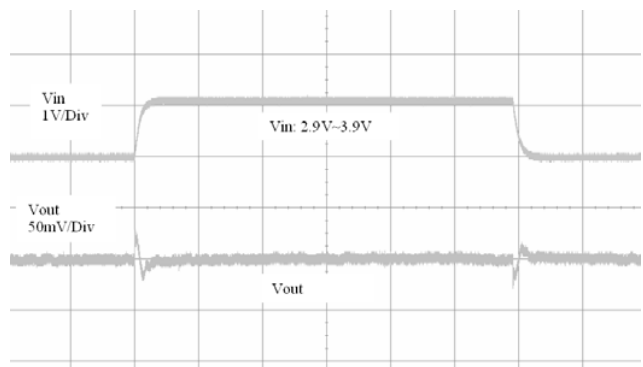
Cout=1µF(Ceramics), Iout=30mA, tr=tf=5µs



**PT7M8424 (2.8V)**

50µs/div

Cin= Cout=1µF(Ceramics), Iout=30mA, tr=tf=5µs

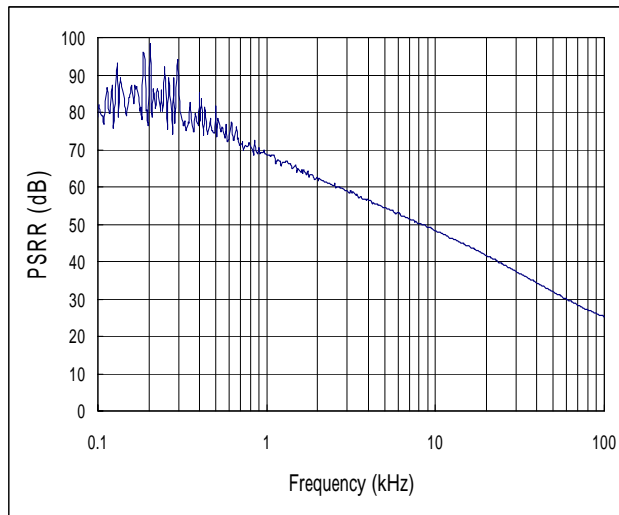


**9. Ripple Rejection**

**PT7M8424 (2.8V)**

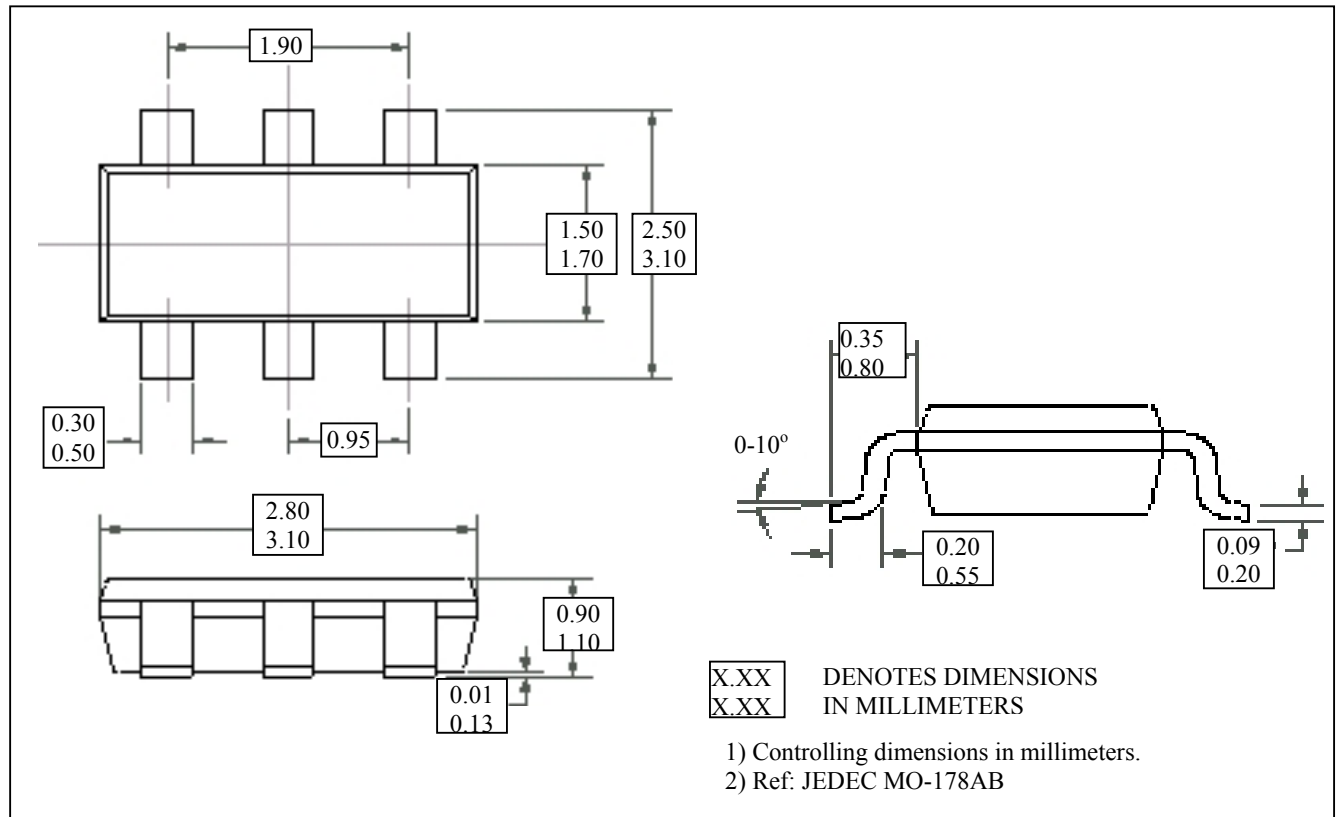
Vin=3.8V DC+1Vp-pAC

Cin= Cout=1µF (Ceramics), Iout=30mA



**Mechanical Information**

TA6E (Lead free and Green SOT23-6L)



**Notes**

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***Pericom Technology Inc.***

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